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				DOCKET NO	
APPLICATION NO.	FILING DATE FIRST NAMED INVENTOR		OINVENTOR	ATTORNEY DOCKET NO.	
		HAMADA	K	PM 271420	
09/663,340	09/15/00	111111111111111111111111111111111111111	7	EXAMINER	
000909 PILLSBURY WINTHROP LLP 1600 TYSONS BOULEVARD		MMC2/1107	MOM Al	RT UNIT PAPER NUMBER	
MCLEAN VA 22	2102	·	283 DATE	26 M ailed: 11/07/01	

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

PTO-90C (Rev. 2/95) *U S GPO 2000-473-000/44602 1- File Copy

		Applicati n No).	Applicant(s)				
٠,	•	09/663,340	_	HAMADA, KIMIMORI				
Office Action Summary		Examiner		Art Unit				
•		Johannes P Mo	ondt	2826				
	- The MAILING DATE of this communication a	appears on the cov	er sheet with the	correspondence address				
ariad fai	r Reply							
THE N - Exten after S - If the - If NO - Failur	ORTENED STATUTORY PERIOD FOR REF MAILING DATE OF THIS COMMUNICATION sions of time may be available under the provisions of 37 CFR SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a re period for reply is specified above, the maximum statutory period et o reply within the set or extended period for reply will, by state apply received by the Office later than three months after the main dipatent term adjustment. See 37 CFR 1.704(b).	1.136(a). In no event, ho reply within the statutory iod will apply and will exp	nwever, may a reply be minimum of thirty (30) of the SIX (6) MONTHS for	timely filed lays will be considered timely. om the mailing date of this communication. NED (35 U.S.C. § 133).				
1)[]	Responsive to communication(s) filed on _	·						
2a)□	This action is FINAL 2b)	This action is nor	n-final.					
3)□	The second transfer of the control o							
•	ion of Claims							
4)⊠	Claim(s) 1-18 is/are pending in the applica	ation.						
	4a) Of the above claim(s) is/are with	drawn from consid	deration.					
5)[Claim(s) is/are allowed.							
6)□	Claim(s) is/are rejected.							
7)🛛	Claim(s) <u>1-18</u> is/are objected to.							
8)[Claim(s) are subject to restriction ar	nd/or election requ	urement.					
	tion Papers							
9)🛛	The specification is objected to by the Exan	miner.	· · · · · · · · · · · · · · · · · · ·	Evaminar				
10)	The drawing(s) filed on is/are: a) a	accepted or b) ob	jected to by the t	See 37 CFR 1 85(a).				
	Applicant may not request that any objection	to the drawing(s) be	round h) disa	noroved by the Examiner.				
11)[The proposed drawing correction filed on _	is: a) app	e action	pp, 0 v 0 u u y =				
	If approved, corrected drawings are required		e doubli.					
•	The oath or declaration is objected to by th	ie Laminer.						
Priority	under 35 U.S.C. §§ 119 and 120	i priority unde	or 3511.S.C. & 1	19(a)-(d) or (f).				
	Acknowledgment is made of a claim for fo	oreign priority und	5, 33 0.0.0. 3 .	, , , , , , , , , , , , , , , , , , , ,				
а	n) ☐ All b) ☐ Some * c) ☐ None of:	mente have been	received					
1. Certified copies of the priority documents have been received.								
	2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage							
,	application from the Internation	a list of the certific	ed copies not re	ceived.				
14)	Acknowledgment is made of a claim for do	mestic priority und	der 35 U.S.C. §	119(e) (to a provisional application)				
ļ	a) The translation of the foreign language Acknowledgment is made of a claim for do	ne provisional app	lication has bee	n received.				
Attachm								
1) 🛛 No	otice of References Cited (PTO-892) otice of Draftsperson's Patent Drawing Review (PTO-94 formation Disclosure Statement(s) (PTO-1449) Paper N	48)	4) Interview Su 5) Notice of Inf 6) Other:	mmary (PTO-413) Paper No(s) ormal Patent Application (PTO-152)				
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Art Unit: 2826

DETAILED ACTION

Information Disclosure Statement

The examiner has considered the items listed in the Information Disclosure Statement of Paper No. 3.

Specification

The phrase "ladder-like" in the abstract (line 8) and everywhere in the "Detailed Description of Preferred Embodiment" (e.g., page 5) is vague and should be replaced by the phrase "ladder-shaped". The phrase "formed at a less depth" in the abstract should be replaced by "formed at a shallower depth".

Claim Objections

- 1. Claims 1-12 are objected to because of the following informalities:

 With regard to claim 1:
- (a) From the specification it is clear that the surface referred to on line 10 of page 10 on which this claim is formulated is *that* surface (out of the two major surfaces) of the body region that is *not* shared with the semiconductor substrate referred to on line 4 on the same page. However, nothing in the claim language clarifies this interpretation of the term "surface". The resulting lack of clarity can be removed by adding to the phrase "forming a body region of a first conductivity type formed in a semiconductor substrate" (lines 3 and 4 of page 10) the following text: "and having a major surface opposite to the surface shared between the semiconductor substrate and the body region"; said lack of

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Art Unit: 2826

clarity can then be removed by referring subsequently to "said major surface" instead of "a surface of the body region" on line 10. Appropriate correction is required.

- (b) The phrase "the gate-insulating films" on line 11 is lacking antecedent basis and should be replaced by "films bordering and insulating the trench gates".
- (c) The term "sandwiching the trench gates" needs to be made clearer. This could be done in accordance with the specification by replacing said term with "flanking the trench gates on both of their sides and being in contact with said trench gates through said films".

Claims 2-12 are objected to because of their dependence, directly or indirectly, on claim that is objected to, namely claim 1.

2. Claims 2, 3, 6, 7, 10, 11, 14, and 15 are objected to under 37 CFR 1.75(b), as being of improper dependent form for failing to further limit the subject matter of a previous claim. In particular, claim 1 proscribes the first semiconductor regions to sandwich the trench gates via the gate-insulating films, while in spite of the dependence of claim 2 on claim 1 the entire further limitation of claim 2 proscribes a portion of the first semiconductor regions to sandwich the trench gates via the gate-insulating films, which proscription is thus automatically met through the dependence of claim 2 on claim 1. Applicant is required to cancel claim 2 for the reason given above. Claims 3, 6, 7, 10, and 11 depend on claim 2 and thus should also be canceled. Claim 14 is objected to because its dependence on claim 13 already implies the proscription that forms the sole

Art Unit: 2826

further limitation of claim 14, in full analogy with the objection against claim 2 given above. Claim 15 is objected to because it depends on claim 14.

- 3. Claims 13-18 are objected to because of the following informalities: with regard to claim 13:
- (a) From the specification it is clear that the surface referred to on line 25 of page 12 on which this claim is formulated is *that* surface (out of the two major surfaces) of the body region that is *not* shared with the semiconductor substrate referred to on line 19 on the same page. However, nothing in the claim language clarifies this interpretation of the term "surface". The resulting lack of clarity can be removed by adding to the phrase "forming a body region of a first conductivity type formed in a semiconductor substrate" (lines 18 and 19 of page 12) the following text: "and having a major surface opposite to the surface shared between the semiconductor substrate and the body region"; said lack of clarity can then be removed by referring subsequently to "said major surface" instead of "a surface of the body region" on line 25, and likewise, on page 13, line 2, by referring to "said major surface" instead of "the surface". Appropriate correction is required.
- (b) The expression "sandwich the trench gates" should be replaced by "flank the trench gates on both of their sides and are in contact with said trench gates through gate-insulating films". Appropriate action is required.

Claims 14-18 are objected to because of their dependence on a claim that is objected to, namely claim 13.

Art Unit: 2826

4. Claims 4 and 16 are objected to because of the following informalities: "ladder-like" should be changed to "ladder-shaped" to avoid indefinite language. See also the objection against the specification. Appropriate correction is required.

Allowable Subject Matter

Claims 1-14 contain allowable subject matter. The following is a statement of reasons for the indication of allowable subject matter:

Unlike the present invention by Applicant, Williams does not teach the areas of the semiconductor regions between the trench gates to be deeper in the immediate vicinity of the trench gates and shallower in the area farther away from the trench gates so as to further reduce parasitic transistor operation.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Johannes P Mondt whose telephone number is 703-306-0531. The examiner can normally be reached on 8:00 - 18:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan J Flynn can be reached on 703-308-6601. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7724 for After Final communications.

Art Unit: 2826

Page 6

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

JPM November 5, 2001

> Nathan Shini Print y Edicion